

# TN5325K1-G

### **TN5325K1-G Information**



E-mail: salesdept@heisener.com



**Request a Quote** 

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## **TN5325K1-G Specifications**

Manufacturer Part Number	TN5325K1-G
Manufacturer	Microchip Technology
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-236-3, SC-59, SOT-23-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	250V
Current - Continuous Drain (Id) @ 25°C	150mA (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	110pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	360mW (Ta)
Rds On (Max) @ Id, Vgs	7 Ohm @ 1A, 10V
Operating Temperature	-
Mounting Type	Surface Mount
Supplier Device Package	TO-236AB (SOT23)
Package / Case	TO-236-3, SC-59, SOT-23-3
	Report errors?

#### **TN5325K1-G Guarantees**



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE UARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

# TN5325K1-G Payment Methods





If you have any question about TN5325K1-G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com